## NSN 5961-01-029-1019

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-029-1019 **Inclosure Material:** Glass **Overall Length:** Between 0.075 inches and 0.097 inches **Overall Diameter:** Between 0.118 inches and 0.124 inches **End Application:** 19905-tu-511p **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 10.00 microamperes forward current, total rms any acceptable **Special Features:** Total capacitance 15.0 (at-4v, 1 mhz) ct-4 (pf) **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

**Fiig:** A110a0